International **TOR** Rectifier

Static @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
V _{(BR)DSS}	Drain-to-Source Breakdown Voltage	40			V	$V_{GS} = 0V, I_{D} = 250 \mu A$
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient	_	0.028		V/°C	Reference to 25° C, $I_{D} = 1$ mA
R _{DS(on)} SMD	Static Drain-to-Source On-Resistance		1.2	1.6	mΩ	V _{GS} = 10V, I _D = 160A ③
V _{GS(th)}	Gate Threshold Voltage	2.0		4.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
gfs	Forward Transconductance	220			S	$V_{DS} = 10V, I_{D} = 160A$
I _{DSS}	Drain-to-Source Leakage Current	_		20	μA	$V_{DS} = 40V, V_{GS} = 0V$
				250		$V_{DS} = 40V, V_{GS} = 0V, T_{J} = 125^{\circ}C$
I _{GSS}	Gate-to-Source Forward Leakage	_		200	nA	V _{GS} = 20V
	Gate-to-Source Reverse Leakage	_		-200	Ī	V _{GS} = -20V
Q _g	Total Gate Charge	_	170	260	nC	I _D = 160A
Q _{gs}	Gate-to-Source Charge		63		I	V _{DS} = 32V
Q _{gd}	Gate-to-Drain ("Miller") Charge	_	71		Ī	V _{GS} = 10V ③
t _{d(on)}	Turn-On Delay Time		17		ns	$V_{DD} = 20V$
tr	Rise Time		150			I _D = 160A
t _{d(off)}	Turn-Off Delay Time		110		Ι	$R_G = 2.6\Omega$
t _f	Fall Time		105			V _{GS} = 10V ②
L _D	Internal Drain Inductance	_	4.5		nH	Between lead,
						6mm (0.25in.)
Ls	Internal Source Inductance		7.5		Ī	from package
						and center of die contact
C _{iss}	Input Capacitance		6930		pF	$V_{GS} = 0V$
C _{oss}	Output Capacitance		1750		Ī	$V_{DS} = 25V$
C _{rss}	Reverse Transfer Capacitance		970			f = 1.0MHz, See Fig. 5
C _{oss}	Output Capacitance		5740			$V_{GS} = 0V, V_{DS} = 1.0V, f = 1.0MHz$
C _{oss}	Output Capacitance		1570			$V_{GS} = 0V, V_{DS} = 32V, f = 1.0MHz$
C _{oss} eff.	Effective Output Capacitance		2340			$V_{GS} = 0V, V_{DS} = 0V \text{ to } 32V$

Diode Characteristics

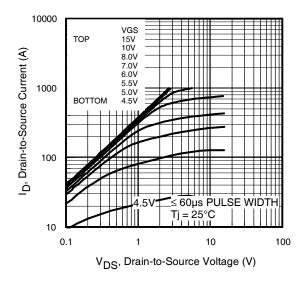
	Parameter	Min.	Тур.	Max.	Units	Conditions
I _S	Continuous Source Current			320		MOSFET symbol
	(Body Diode)				А	showing the
I _{SM}	Pulsed Source Current			1360		integral reverse
	(Body Diode) ①					p-n junction diode.
V _{SD}	Diode Forward Voltage			1.3	V	$T_J = 25^{\circ}C, I_S = 160A, V_{GS} = 0V$ (3)
t _{rr}	Reverse Recovery Time		43	65	ns	$T_J = 25^{\circ}C, I_F = 160A, V_{DD} = 20V$
Q _{rr}	Reverse Recovery Charge		48	72	nC	di/dt = 100A/µs

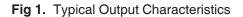
Notes:

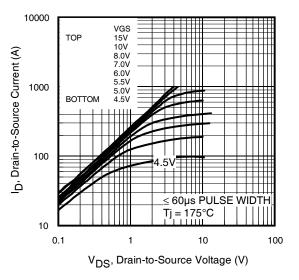
- ① Repetitive rating; pulse width limited by max. junction temperature. (See fig. 11).
- 3 Pulse width \leq 1.0ms; duty cycle \leq 2%.
- G C_{oss} eff. is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 to 80% V_{DSS}.
- ⑤ Limited by T_{Jmax}, see Fig.12a, 12b, 15, 16 for typical repetitive avalanche performance.
- ⑤ This value determined from sample failure population. 100% tested to this value in production.
- ⑦ This is applied to D²Pak, when mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.
- $\circledast~\mathsf{R}_{\theta}$ is measured at T_J of approximately 90°C.

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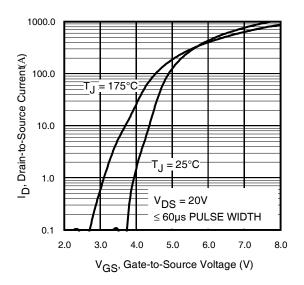
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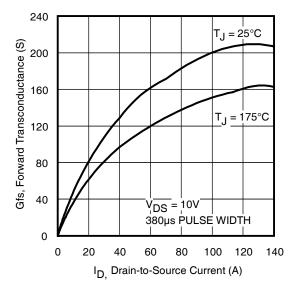
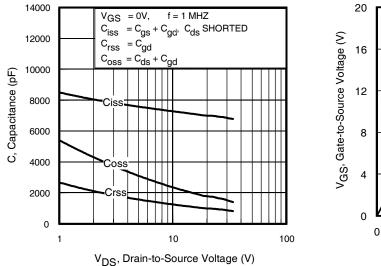
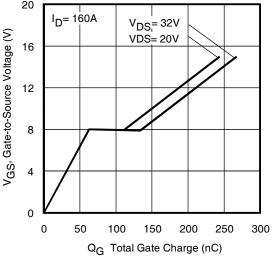


Fig 4. Typical Forward Transconductance vs. Drain Current

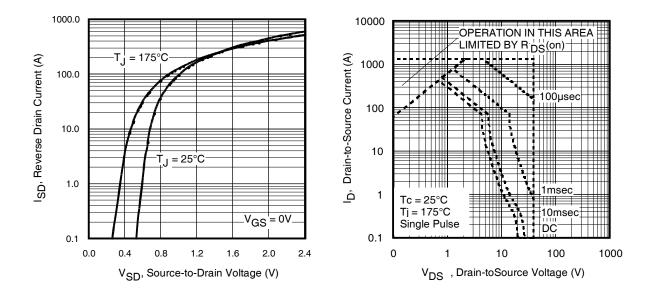
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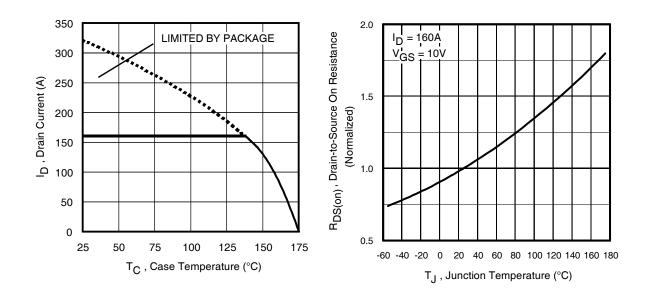


Fig 9. Maximum Drain Current vs. Case Temperature

Fig 10. Normalized On-Resistance vs. Temperature

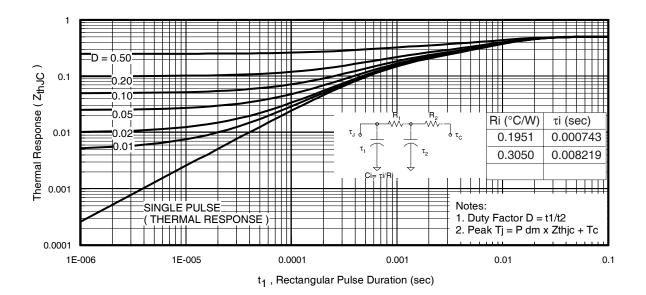


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case

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ΙD

21A

33A

BOTTOM 160A

TOP

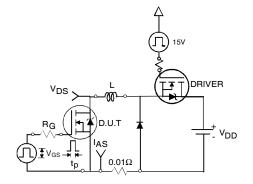
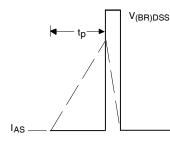


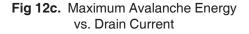
Fig 12a. Unclamped Inductive Test Circuit



 $\mathsf{E}_{\mathsf{AS},}$ Single Pulse Avalanche Energy (mJ) 1500 1000 500 0 25 50 75 100 150 175 125 Starting T_J, Junction Temperature (°C)

2500

2000



 Q_G 10 V Q_{GS} Q_{GD} V_{G} Charge

Fig 12b. Unclamped Inductive Waveforms

Fig 13a. Basic Gate Charge Waveform

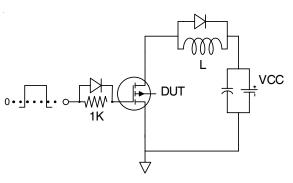
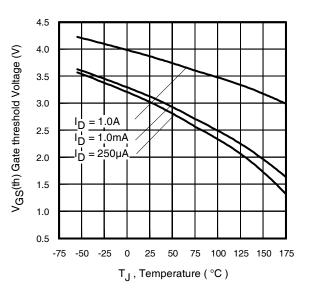


Fig 13b. Gate Charge Test Circuit 6







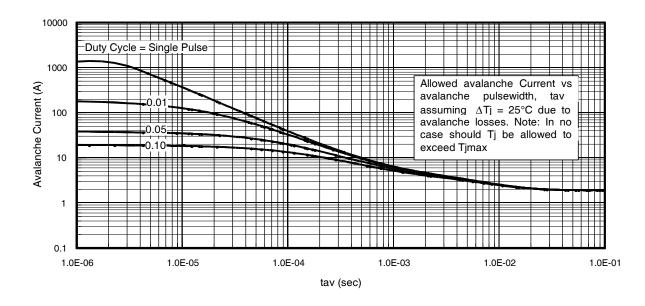
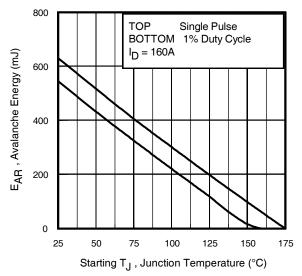


Fig 15. Typical Avalanche Current vs.Pulsewidth





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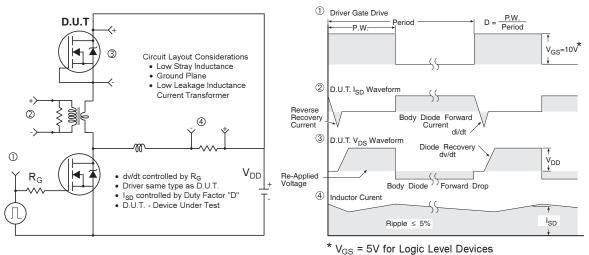
Notes on Repetitive Avalanche Curves , Figures 15, 16: (For further info, see AN-1005 at www.irf.com)

- Avalanche failures assumption: Purely a thermal phenomenon and failure occurs at a temperature far in excess of T_{jmax}. This is validated for every part type.
- Safe operation in Avalanche is allowed as long asT_{jmax} is not exceeded.
- 3. Equation below based on circuit and waveforms shown in Figures 12a, 12b.
- 4. P_{D (ave)} = Average power dissipation per single avalanche pulse.
- 5. BV = Rated breakdown voltage (1.3 factor accounts for voltage increase during avalanche).
- 6. Iav = Allowable avalanche current.
- 7. Δ T = Allowable rise in junction temperature, not to exceed T_{imax} (assumed as 25°C in Figure 15, 16).
 - $t_{av} = Average time in avalanche.$
 - D = Duty cycle in avalanche = $t_{av} \cdot f$

 $Z_{thJC}(D, t_{av}) = Transient thermal resistance, see figure 11)$

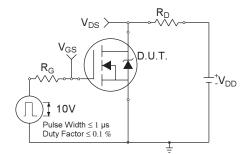
$$\begin{split} \textbf{P}_{D~(ave)} &= 1/2~(~1.3{\cdot}BV{\cdot}I_{av}) = \bigtriangleup T/~Z_{thJC}\\ \textbf{I}_{av} &= 2\bigtriangleup T/~[1.3{\cdot}BV{\cdot}Z_{th}]\\ \textbf{E}_{AS~(AR)} &= \textbf{P}_{D~(ave)}{\cdot}t_{av} \end{split}$$

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Fig 17. Peak Diode Recovery dv/dt Test Circuit for N-Channel HEXFET[®] Power MOSFETs





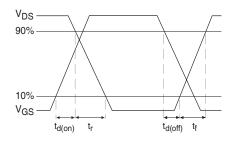


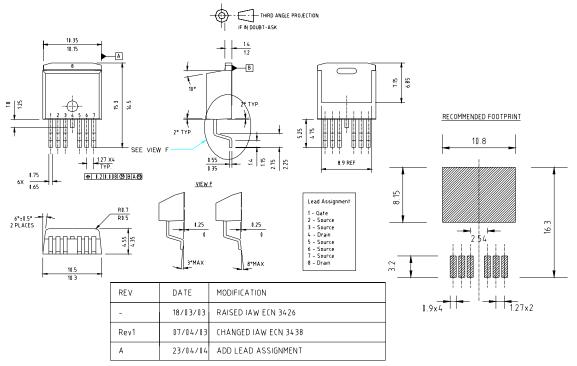
Fig 18b. Switching Time Waveforms

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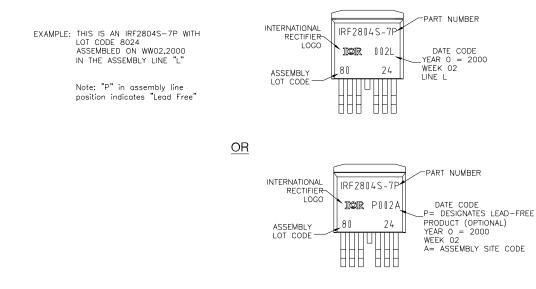
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D²Pak - 7 Pin Package Outline

Dimensions are shown in millimeters (inches)



D²Pak - 7 Pin Part Marking Information



Notes:

 1. For an Automotive Qualified version of this part please see
 http://www.irf.com/product-info/datasheets/data/ auirf2804s-7p.pdf

 2. For the most current drawing please refer to IR website at http://www.irf.com/package/

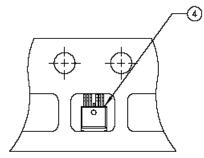
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D²Pak - 7 Pin Tape and Reel

NOTES, TAPE & REEL, LABELLING:

- 1. TAPE AND REEL.
 - 1.1 REEL SIZE 13 INCH DIAMETER.
 - 1.2 EACH REEL CONTAINING BOD DEVICES.
 - 1.3 THERE SHALL BE A MINIMUM OF 42 SEALED POCKETS CONTAINED IN THE LEADER AND A MINIMUM OF 15 SEALED POCKETS IN THE TRAILER.
 - 1.4 PEEL STRENGTH MUST CONFORM TO THE SPEC. NO. 71-9667.
 - 1.5 PART ORIENTATION SHALL BE AS SHOWN BELOW.
 - 1.6 REEL MAY CONTAIN A MAXIMUM OF TWO UNIQUE LOT CODE/DATE CODE COMBINATIONS. REWORKED REELS MAY CONTAIN A MAXIMUM OF THREE UNIQUE LOT CODE/DATE CODE COMBINATIONS. HOWEVER, THE LOT CODES AND DATE CODES WITH THEIR RESPECTIVE QUANTITIES SHALL APPEAR ON THE BAR CODE LABEL FOR THE AFFECTED REEL.

- 2. LABELLING (REEL AND SHIPPING BAG).
 - 2.1 CUST. PART NUMBER (BAR CODE): IRF2804STRL-7P
 - 2.2 CUST. PART NUMBER (TEXT CODE): IRF2804STRL-7P
 - 2.3 I.R. PART NUMBER: IRF2804STRL-7P
 - 2.4 QUANTITY:
 - 2.5 VENDOR CODE: IR
 - 2.6 LOT CODE:
 - 2.7 DATE CODE:
 - LABEL ⓓ



Data and specifications subject to change without notice. This product has been designed and gualified for the Industrial market. Qualification Standards can be found on IR's Web site.

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